

Supporting information

Investigation on voltage loss in organic triplet photovoltaic devices based on Ir complexes

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Table S1 Photophysical Characteristics of Ir(Ftbpa)₃ and Ir(FOtbp)₃.

	Degassed CH ₂ Cl ₂ solution ^a					Neat film			
	$\lambda_{\text{abs}}[\text{nm}]$ [$\varepsilon (\times 10^4 \text{ L mol}^{-1} \text{ cm}^{-1})$]	$\lambda_{\text{em}}[\text{nm}]$	$\Phi_{\text{PL}}^{\text{b}}$ [%]	$\tau_{\text{p}}[\text{ns}]$	$K_{\text{r}}/K_{\text{nr}}$ [$\times 10^5 \text{ s}^{-1}$]	$\lambda_{\text{em}}[\text{nm}]$	$\Phi_{\text{PL}}^{\text{b}}$ [%]	$\tau_{\text{p}}[\text{ns}]$	$K_{\text{r}}/K_{\text{nr}}$ [$\times 10^5 \text{ s}^{-1}$]
Ir(Ftbpa)₃	263 (12.3), 335 (3.5), 355 (3.6), 374 (3.3), 490 (2.3), 550 (1.8)	765, 820(s)	14.7	730	2.0/11.7	784	2.6	19	13.7/512.6
Ir(FOtbp)₃	260 (10.8), 326 (3.0), 349 (2.9), 349 (2.8), 383 (2.1), 472 (1.9), 537 (1.1)	767, 827(s)	10.8	489	2.2/18.2	780	2.4	50	4.9/199.2

^a The concentration of the solution is 2×10^{-5} M. ε denotes the molar extinction coefficients. ^b Φ_{PL} denotes the PLQY.

Table S2 Summary of photovoltaic parameters of T-OPVs based on Ftbpa and FOtbp ligands.

Active layer	V_{oc} (V)	J_{sc} (mA/cm ²)	FF	PCE (%)
Ftbpa:PC ₇₁ BM	0.27	0.02	0.24	0.001
FOtbp:PC ₇₁ BM	0.45	0.04	0.37	0.007

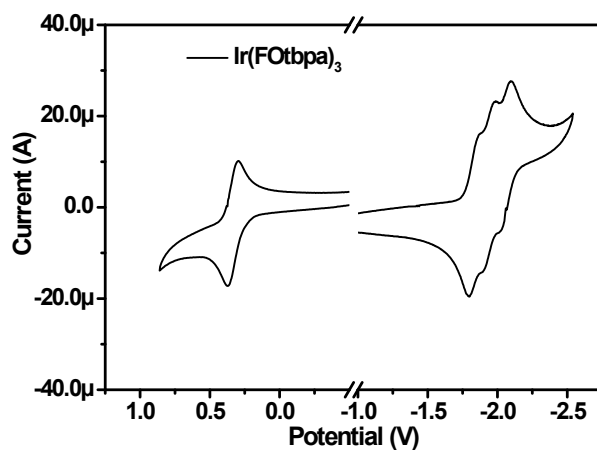


Fig. S1 CV of and $\text{Ir}(\text{FOTbpa})_3$ recorded versus Fc^+/Fc in anhydrous DMF solutions at 298 K under a N_2 atmosphere;

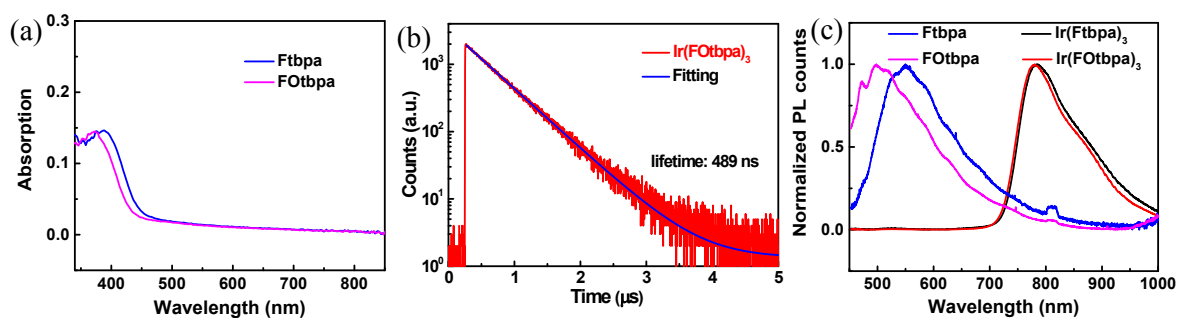


Fig. S2 (a) Absorption spectra of Ftbpa and FOTbpa films; (b) Transient PL decay curves of $\text{Ir}(\text{FOTbpa})_3$ in degassed CH_2Cl_2 solution; (c) Normalized PL spectra of $\text{Ir}(\text{Ftbpa})_3$, $\text{Ir}(\text{FOTbpa})_3$, Ftbpa, and FOTbpa films; The films were excited by a 405 nm laser.

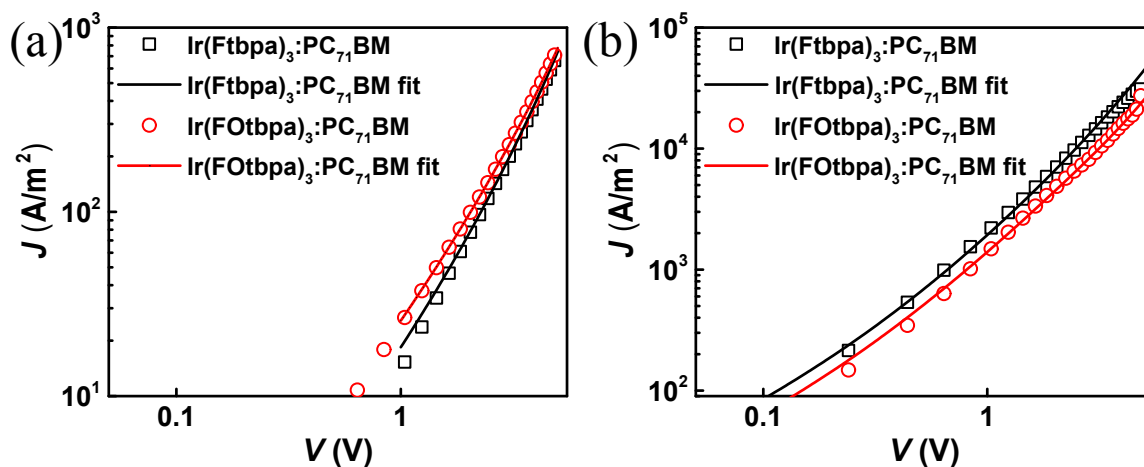


Fig. S3 J - V curves for hole (a) and electron (b) only devices based on $\text{Ir}(\text{Ftbpa})_3:\text{PC}_{71}\text{BM}$ and $\text{Ir}(\text{FOtbpa})_3:\text{PC}_{71}\text{BM}$ blends with a weight ratio of 1:1.5.

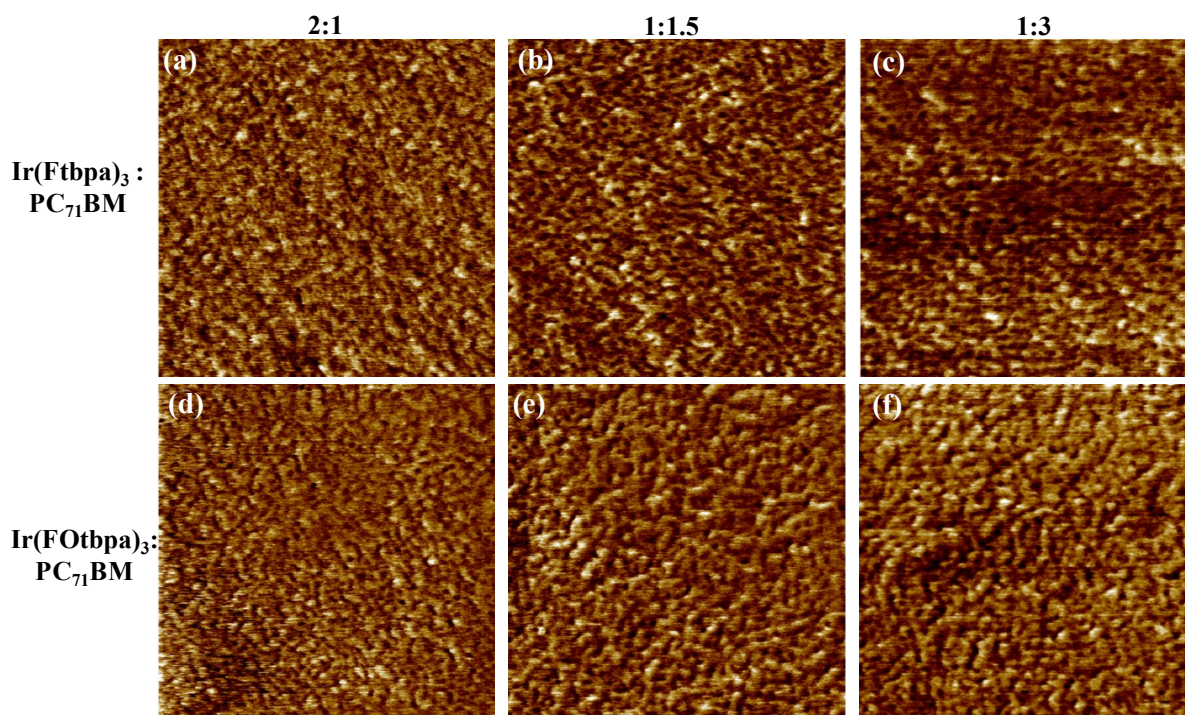


Fig. S4 AFM ($2\ \mu\text{m} \times 2\ \mu\text{m}$) phase images of $\text{Ir}(\text{Ftbpa})_3:\text{PC}_{71}\text{BM}$ blends with weight ratio of 2:1 (a), 1:1.5 (b), 1:3 (c) and $\text{Ir}(\text{FOtbpa})_3:\text{PC}_{71}\text{BM}$ blends with weight ratio of 2:1 (d), 1:1.5 (e), 1:3 (f).

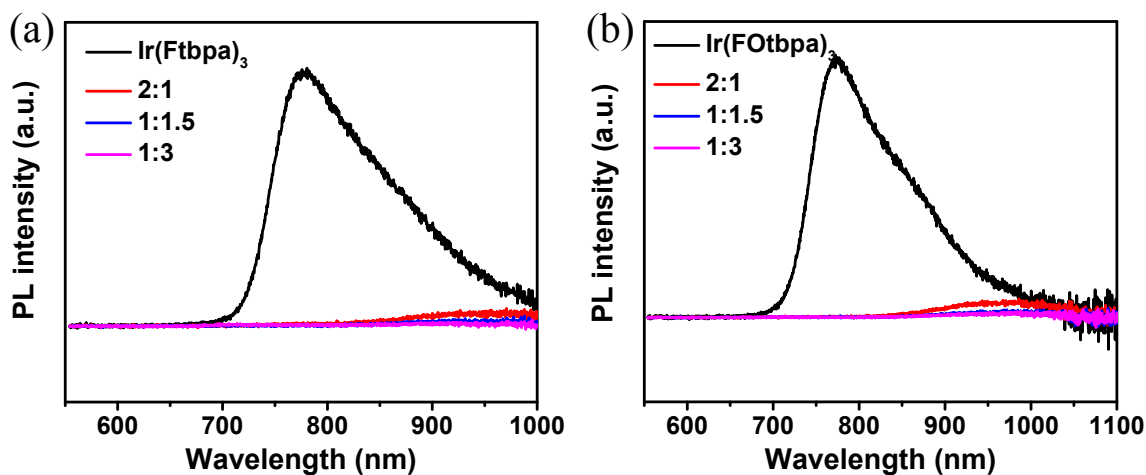


Fig. S5 (a) PL spectra of the pristine $\text{Ir}(\text{Ftbpa})_3$ and blended films with different weight ratios. (b) PL spectra of the pristine $\text{Ir}(\text{FOtbpa})_3$ and blended films with different weight ratios. The PL intensities are corrected by their absorptions at the excitation wavelength (532 nm).

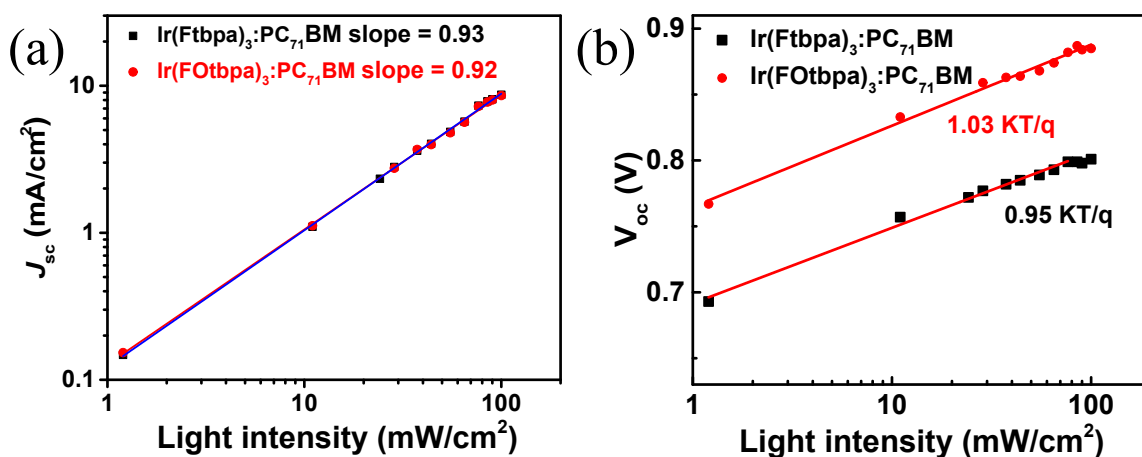


Fig. S6 (a) J_{sc} and (b) V_{oc} versus light intensity for T-OPVs based on $\text{Ir}(\text{Ftbpa})_3:\text{PC}_{71}\text{BM}$ blends (1:1.5) and $\text{Ir}(\text{FOtbpa})_3:\text{PC}_{71}\text{BM}$ blends (1:1.5).